Green-Mode Power Switch

Description

The FSGM0765R is an integrated Pulse Width Modulation (PWM) controller and SENSEFET® specifically designed for offline Switch-Mode Power Supplies (SMPS) with minimal external components. The PWM controller includes an integrated fixed-frequency oscillator, Under-Voltage Lockout (UVLO), Leading-Edge Blanking (LEB), optimized gate driver, internal soft-start, temperature-compensated precise current sources for loop compensation, and self-protection circuitry. Compared with a discrete MOSFET and PWM controller solution, the FSGM series can reduce total cost, component count, size, and weight; while simultaneously increasing efficiency, productivity, and system reliability. This device provides a basic platform suited for cost-effective design of a flyback converter.

Features

- Soft Burst-Mode Operation for Low Standby Power Consumption and Low Noise
- Precision Fixed Operating Frequency: 66 kHz
- Pulse-by-Pulse Current Limit
- Various Protection Functions: Overload Protection (OLP),
 Over-Voltage Protection (OVP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD) with Hysteresis,
 Output-Short Protection (OSP), and Under-Voltage Lockout (UVLO) with Hysteresis
- Auto-Restart Mode
- Internal Startup Circuit
- Internal High-Voltage SENSEFET: 650 V
- Built-in Soft-Start: 15 ms
- These are Pb-Free Devices

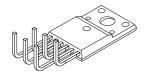
Applications

 Power Supply for LCD TV and Monitor, STB and DVD Combination

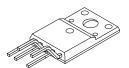


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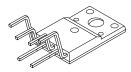
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TO-220-6LD LF CASE 340BN

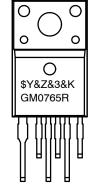


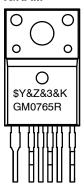
TO-220-6LD LF CASE 340BG



TO-220 FULLPAK 6LD LF CASE 340BP

MARKING DIAGRAM





\$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = 3-Digit Date Code Format &K = 2-Digit Lot Run Tracebility Code GM0765R = Specific Device Code Data

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ORDERING INFORMATION

					Output Power	Table (Note 2)				
		0			230V _{AC} ± 1	5% (Note 3)	85 – 2	65 V _{AC}	1	
Part Number	Package	Operating Junction Temperature	Current Limit	R _{DS(ON)} (Max.)	Adapter (Note 4)	Open Frame (Note 5)	Adapter (Note 4)	Open Frame (Note 5)	Replaces Device	Shipping
FSGM0765RWDTU	TO-220F 6-Lead (Note 1) W-Forming	–40°C ∼ +125°C	2.60 A	2.6 Ω	80 W	90 W	48 W	70 W	FSDM07652RE	400 / Tube
FSGM0765RUDTU	TO-220F 6-Lead (Note 1) U-Forming	-40°C ∼ +125°C	2.60 A	2.6 Ω	80 W	90 W	48 W	70 W	FSDM07652RE	400 / Tube
FSGM0765RLDTU	TO-220F 6-Lead (Note 1) L-Forming	-40°C ∼ +125°C	2.60 A	2.6 Ω	80 W	90 W	48 W	70 W	FSDM07652RE	400 / Tube

- Pb-free package per JEDEC J-STD-020B.
 The junction temperature can limit the maximum output power.
 230 V_{AC} or 100 / 115 V_{AC} with voltage doubler.
- 4. Typical continuous power in a non-ventilated enclosed adapter measured at 50°C ambient temperature.
- 5. Maximum practical continuous power in an open-frame design at 50°C ambient temperature.

Application Circuit

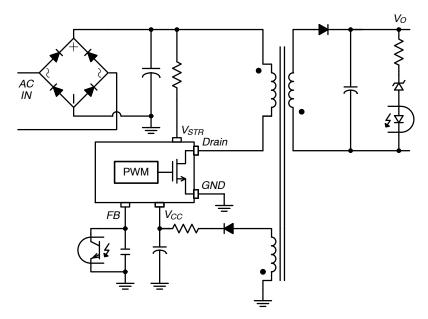


Figure 1. Typical Application Circuit

Internal Block Diagram

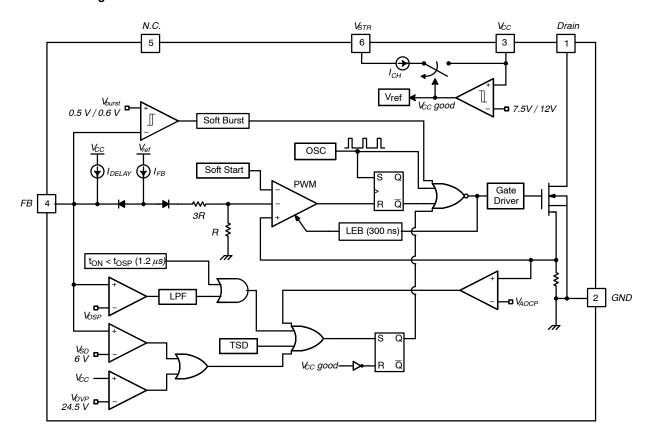


Figure 2. Internal Block Diagram

Pin Configuration

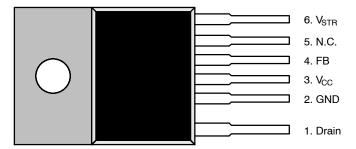


Figure 3. Pin Configuration (Top View)

PIN DEFINITIONS

Pin No.	Name	Description
1	Drain	SENSEFET Drain. High-voltage power SENSEFET drain connection.
2	GND	Ground. This pin is the control ground and the SENSEFET source.
3	V _{CC}	Power Supply. This pin is the positive supply input, which provides the internal operating current for both startup and steady-state operation.
4	FB	Feedback. This pin is internally connected to the inverting input of the PWM comparator. The collector of an opto-coupler is typically tied to this pin. For stable operation, a capacitor should be placed between this pin and GND. If the voltage of this pin reaches 6 V, the overload protection triggers, which shuts down the power switch.
5	N.C.	No Connection.
6	V _{STR}	Startup. This pin is connected directly, or through a resistor, to the high-voltage DC link. At startup, the internal high-voltage current source supplies internal bias and charges the external capacitor connected to the V_{CC} pin. Once V_{CC} reaches 12 V, the internal current source (I_{CH}) is disabled.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parame	ter	Min	Max	Unit
V _{STR}	V _{STR} Pin Voltage	V _{STR} Pin Voltage			V
V _{DS}	Drain Pin Voltage		-	650	V
V _{CC}	V _{CC} Pin Voltage		-	26	V
V_{FB}	Feedback Pin Voltage		-0.3	12.0	V
I _{DM}	Drain Current Pulsed			12.8	Α
I _{DS}	Continuous Switching Drain Current (Note 6)	Continuous Switching Drain Current (Note 6) T _C = +25°C		6.4	Α
	T _C = +100°C		-	4.0	Α
E _{AS}	Single Pulsed Avalanche Energy (Note 7)			390	mJ
P _D	Total Power Dissipation (T _C = +25°C) (Note 8)		-	45	W
TJ	Maximum Junction Temperature		-	+150	°C
	Operating Junction Temperature (Note 9)		-40	+125	°C
T _{STG}	Storage Temperature			+150	°C
V _{ISO}	Minimum Isolation Voltage (Note 10)			-	V
ESD	Electrostatic Discharge Capability Human Body Model, JESD22-A114		2	_	kV
		Charged Device Model, JESD22-C101	2	-	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Repetitive peak switching current when the inductive load is assumed: Limited by maximum duty (D_{MAX} = 0.75) and junction temperature (see Figure 4).
- 7. L = 70 mH, starting T_J = +25°C.
 8. Infinite cooling condition (refer to the SEMI G30–88).
- 9. Although this parameter guarantees IC operation, it does not guarantee all electrical characteristics.
- 10. The voltage between the package back side and the lead is guaranteed.

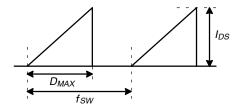


Figure 4. Repetitive Peak Switching Current

THERMAL CHARACTERISTICS

Symbol	Characteristic	Value	Unit
$\theta_{\sf JA}$	Junction-to-Ambient Thermal Impedance (Note 11)	62.5	°C/W
$\theta_{\sf JC}$	Junction-to-Case Thermal Impedance (Note 12)	3	°C/W

ELECTRICAL CHARACTERISTICS (T₁ = +25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
SENSEFET	SECTION				•	
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{CC} = 0 \text{ V}, I_D = 250 \mu\text{A}$	650	-	-	V
I _{DSS}	Zero-Gate-Voltage Drain Current	V _{DS} = 520 V, T _A = +125°C	-	-	250	μΑ
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} = 10 V, I _D = 1 A	-	1.3	1.6	Ω
C _{ISS}	Input Capacitance (Note 13)	V _{DS} = 25 V, V _{GS} = 0 V, f = 1MHz	-	674	-	pF
C _{OSS}	Output Capacitance (Note 13)	V _{DS} = 25 V, V _{GS} = 0 V, f = 1MHz	-	93	-	pF
t _r	Rise Time	V_{DS} = 325 V, I_D = 4 A, R_G = 25 Ω	-	30	-	ns
t _f	Fall Time	$V_{DS} = 325 \text{ V}, I_{D} = 4 \text{ A}, R_{G} = 25 \Omega$	-	26	-	ns
t _{d(on)}	Turn-On Delay Time	V_{DS} = 325 V, I_{D} = 4 A, R_{G} = 25 Ω	-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{DS} = 325 \text{ V}, I_{D} = 4 \text{ A}, R_{G} = 25 \Omega$	-	39	_	ns
CONTROL	SECTION					
f _S	Switching Frequency	V _{CC} = 14 V, V _{FB} = 4 V	60	66	72	kHz
Δf_{S}	Switching Frequency Variation (Note 13)	−25°C < T _J < +125°C	-	±5	±10	%
D _{MAX}	Maximum Duty Ratio	V _{CC} = 14 V, V _{FB} = 4 V	65	70	75	%
D _{MIN}	Minimum Duty Ratio	V _{CC} = 14 V, V _{FB} = 0 V	-	-	0	%
I _{FB}	Feedback Source Current	V _{FB} = 0	160	210	260	μΑ
V _{START}	UVLO Threshold Voltage	V _{FB} = 0 V, V _{CC} Sweep	11	12	13	٧
V _{STOP}		After Turn-on, V _{FB} = 0 V	7.0	7.5	8.0	٧
V _{OP}	V _{CC} Operating Range		13	-	23	٧
t _{S/S}	Internal Soft-Start Time	V _{STR} = 40 V, V _{CC} Sweep	-	15	-	ms
BURST-MO	DE SECTION					
V _{BURH}	Burst-Mode Voltage	V _{CC} = 14 V, V _{FB} Sweep	0.5	0.6	0.7	٧
V _{BURL}			0.3	0.4	0.5	٧
Hys]		-	200	-	mV
PROTECTIO	ON SECTION					
I _{LIM}	Peak Drain Current Limit	di/dt = 300 mA/μs	2.37	2.60	2.83	Α
V_{SD}	Shutdown Feedback Voltage	V _{CC} = 14 V, V _{FB} Sweep	5.5	6.0	6.5	٧
I _{DELAY}	Shutdown Delay Current	V _{CC} = 14 V, V _{FB} = 4 V	2.5	3.3	4.1	μΑ
Hys	Leading-Edge Blanking Time (Note 13, 14)		-	300	-	ns
V _{OVP}	Over-Voltage Protection	V _{CC} Sweep	23.0	24.5	26.0	V

^{11.} Infinite cooling condition *(refer to the SEMI G30–88)*.
12. Free standing with no heat–sink under natural convection.

ELECTRICAL CHARACTERISTICS (T_{.I} = +25°C unless otherwise noted) (continued)

Symbol	Parameter		Test Condition	Min	Тур	Max	Unit
PROTECTIO	ON SECTION			•		•	
t _{OSP}	Output Short	Threshold Time	OSP Triggered when ton < tosp &	1.0	1.2	1.4	μs
V _{OSP}	Protection (Note 13)	Threshold V _{FB}	V _{FB} > V _{OSP} (Lasts Longer than tosp_FB)	1.8	2.0	2.2	V
t _{OSP_FB}]	V _{FB} Blanking Time		2.0	2.5	3.0	μs
T _{SD}	Thermal Shutdown Temperature (Note 13)		Shutdown Temperature	+130	+140	+150	°C
Hys			Hysteresis	-	+30	-	°C
TOTAL DEV	ICE SECTION						
I _{OP}	Operating Supply Current, (Control Part in Burst Mode)		V _{CC} = 14 V, V _{FB} = 0 V	1.2	1.6	2.0	mA
I _{OPS}	Operating Switching Current, (Control Part and SENSEFET Part)		V _{CC} = 14 V, V _{FB} = 4 V	2.0	2.5	3.0	mA
I _{START}	Start Current		V _{CC} = 11 V (Before V _{CC} Reaches V _{START})	0.5	0.6	0.7	mA
I _{CH}	Startup Charging Current		V _{CC} = V _{FB} = 0 V, V _{STR} = 40 V	1.00	1.15	1.50	mA
V _{STR}	Minimum V _{STR} Supply	v Voltage	V _{CC} = V _{FB} = 0 V, V _{STR} Sweep	-	26	-	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 1. COMPARISON OF FSDM07652RE AND FSGM0765R

Function	FSDM07652RE	FSGM0765R	Advantages of FSGM0765R
Burst Mode	Advanced Burst	Advanced Soft Burst	Low noise and low standby power
Lightning Surge		Strong	Enhanced SENSEFET and controller against lightning surge
Soft-Start	10 ms (Built-in)	15 ms (Built-in)	Longer soft-start time
Protections	OLP OVP TSD	OLP OVP OSP AOCP TSD with Hysteresis	Enhanced protections and high reliability
Power Balance	Long T _{CLD}	Very Short T _{CLD}	The difference of input power between the low and high input voltage is quite small

^{13.} Although these parameters are guaranteed, they are not 100% tested in production.

^{14.} t_{LEB} includes gate turn-on time.

TYPICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

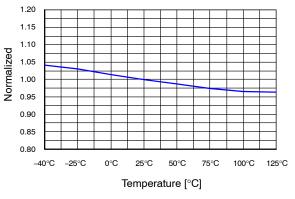


Figure 5. Operating Supply Current (I_{OP}) vs. T_A

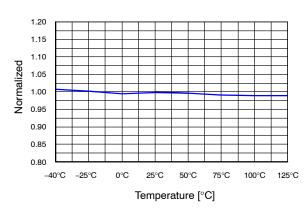


Figure 6. Operating Switching Current (I_{OPS}) vs. T_A

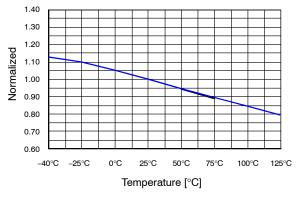


Figure 7. Startup Charging Current (I_{CH}) vs. T_A

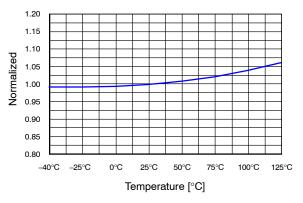


Figure 8. Peak Drain Current Limit (I_{LIM}) vs. T_A

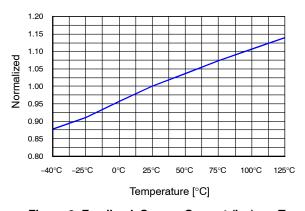


Figure 9. Feedback Source Current (I_{FB}) vs. T_A

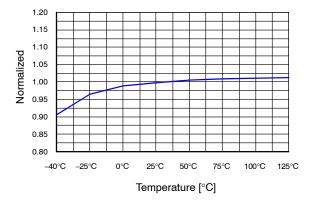
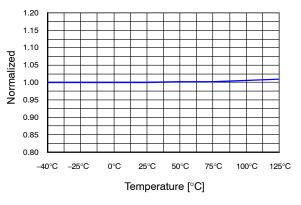


Figure 10. Shutdown Delay Current (I_{DELAY}) vs. T_A

TYPICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)



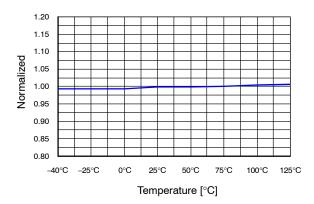
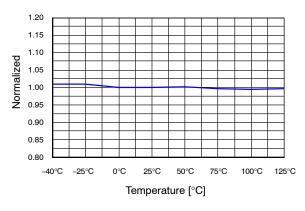


Figure 11. UVLO Threshold Voltage (V_{START}) vs. T_A

Figure 12. UVLO Threshold Voltage (V_{STOP}) vs. T_A



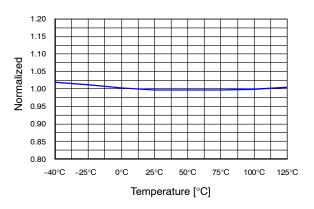
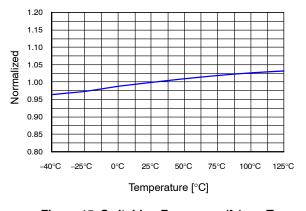


Figure 13. Shutdown Feedback Voltage (V_{SD}) vs. T_A

Figure 14. Over-Voltage Protection (V_{OVP}) vs. T_A



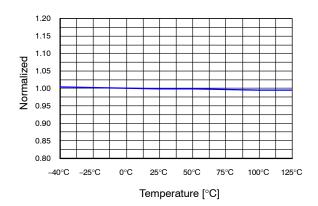


Figure 15. Switching Frequency (f_S) vs. T_A

Figure 16. Maximum Duty Ratio (D_{MAX}) vs. T_A

FUNCTIONAL DESCRIPTION

Startup

At startup, an internal high–voltage current source supplies the internal bias and charges the external capacitor (C_V cc) connected to the V_{CC} pin, as illustrated in Figure 17. When V_{CC} reaches 12 V, the FSGM0765R begins switching and the internal high–voltage current source is disabled. The FSGM0765R continues normal switching operation and the power is supplied from the auxiliary transformer winding unless V_{CC} goes below the stop voltage of 7.5 V.

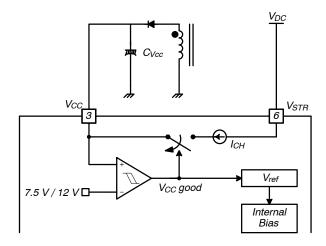


Figure 17. Startup Block

Soft-Start

The FSGM0765R has an internal soft-start circuit that increases PWM comparator inverting input voltage, together with the SENSEFET current, slowly after it starts. The typical soft-start time is 15 ms. The pulse width to the power switching device is progressively increased to establish the correct working conditions for transformers, inductors, and capacitors. The voltage on the output capacitors is progressively increased to smoothly establish

the required output voltage. This helps prevent transformer saturation and reduces stress on the secondary diode during startup.

Feedback Control

This device employs current-mode control, as shown in Figure 18. An opto-coupler (such as the FOD817) and shunt regulator (such as the KA431) are typically used to implement the feedback network. Comparing the feedback voltage with the voltage across the R_{SENSE} resistor makes it possible to control the switching duty cycle. When the reference pin voltage of the shunt regulator exceeds the internal reference voltage of 2.5 V, the opto-coupler LED current increases, pulling down the feedback voltage and reducing drain current. This typically occurs when the input voltage is increased or the output load is decreased.

Pulse-by-Pulse Current Limit

Because current– mode control is employed, the peak current through the SENSEFET is limited by the inverting input of PWM comparator (V_{FB}^*), as shown in Figure 18. Assuming that the 210 μ A current source flows only through the internal resistor (3R + R = 11.6 k Ω), the cathode voltage of diode D2 is about 2.4 V. Since D1 is blocked when the feedback voltage (V_{FB}) exceeds 2.4 V, the maximum voltage of the cathode of D2 is clamped at this voltage. Therefore, the peak value of the current through the SENSEFET is limited.

Leading-Edge Blanking (LEB)

At the instant the internal SENSEFET is turned on, a high-current spike usually occurs through the SENSEFET, caused by primary-side capacitance and secondary-side rectifier reverse recovery. Excessive voltage across the RSENSE resistor leads to incorrect feedback operation in the current mode PWM control. To counter this effect, the FSGM0765R employs a leading-edge blanking (LEB) circuit. This circuit inhibits the PWM comparator for tLEB (300 ns) after the SENSEFET is turned on.

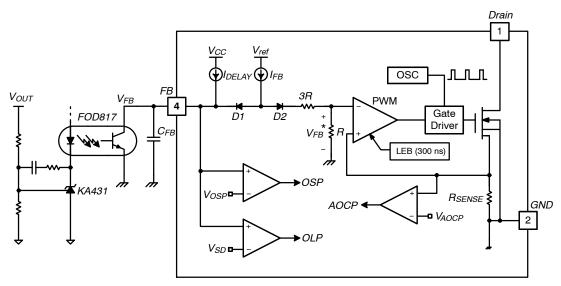


Figure 18. Pulse Width Modulation Circuit

Protection Circuits

The FSGM0765R has several self-protective functions, as Overload Protection (OLP), Abnormal Over-Current Protection (AOCP), Output-Short Protection (OSP), Over-Voltage Protection (OVP), and Thermal Shutdown (TSD). All the protections are implemented as auto-restart. Once the fault condition is detected, switching is terminated and the SENSEFET remains off. This causes V_{CC} to fall. When V_{CC} falls to the Under-Voltage Lockout (UVLO) stop voltage of 7.5 V, the protection is reset and the startup circuit charges the V_{CC} capacitor. When V_{CC} reaches the start voltage of 12.0 V, the FSGM0765R resumes normal operation. If the fault condition is not removed, the SENSEFET remains off and V_{CC} drops to stop voltage again. In this manner, the auto-restart can alternately enable and disable the switching of the power SENSEFET until the fault condition is eliminated. Because these protection circuits are fully integrated into the IC without external components, the reliability is improved without increasing cost.

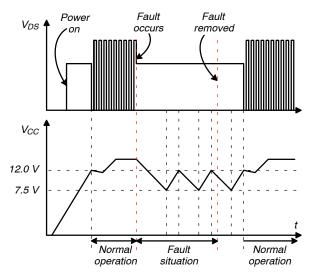


Figure 19. Auto-Restart Protection Waveforms

Overload Protection (OLP)

Overload is defined as the load current exceeding its normal level due to an unexpected abnormal event. In this situation, the protection circuit should trigger to protect the SMPS. However, even when the SMPS is in normal operation, the overload protection circuit can be triggered during the load transition. To avoid this undesired operation, the overload protection circuit is designed to trigger only after a specified time to determine whether it is a transient situation or a true overload situation. Because of the pulse-by-pulse current limit capability, the maximum peak current through the SENSEFET is limited and, therefore, the maximum input power is restricted with a given input voltage. If the output consumes more than this maximum power, the output voltage (VOUT) decreases below the set voltage. This reduces the current through the opto-coupler LED, which also reduces the opto-coupler transistor

current, thus increasing the feedback voltage (V_{FB}). If V_{FB} exceeds 2.4 V, D1 is blocked and the 3.3 μA current source starts to charge C_{FB} slowly up. In this condition, V_{FB} continues increasing until it reaches 6.0 V, when the switching operation is terminated, as shown in Figure 20. The delay time for shutdown is the time required to charge C_{FB} from 2.4 V to 6.0 V with 3.3 μA . A 25 ~ 50 ms delay is typical for most applications. This protection is implemented in auto-restart mode.

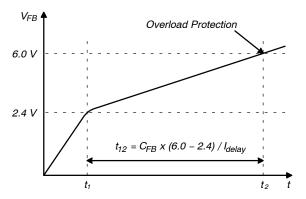


Figure 20. Overload Protection

Abnormal Over-Current Protection (AOCP)

When the secondary rectifier diodes or the transformer pins are shorted, a steep current with extremely high di/dt can flow through the SENSEFET during the minimum turn—on time. Even though the FSGM0765R has overload protection, it is not enough to protect the FSGM0765R in that abnormal case; since severe current stress is imposed on the SENSEFET until OLP is triggered. The FSGM0765R internal AOCP circuit is shown in Figure 21. When the gate turn—on signal is applied to the power SENSEFET, the AOCP block is enabled and monitors the current through the sensing resistor. The voltage across the resistor is compared with a preset AOCP level. If the sensing resistor voltage is greater than the AOCP level, the set signal is applied to the S–R latch, resulting in the shutdown of the SMPS.

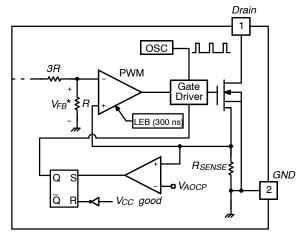


Figure 21. Abnormal Over-Current Protection

Output-Short Protection (OSP)

If the output is shorted, steep current with extremely high di/dt can flow through the SENSEFET during the minimum turn—on time. Such a steep current brings high—voltage stress on the drain of the SENSEFET when turned off. To protect the device from this abnormal condition, OSP is included. It is comprised of detecting V_{FB} and SENSEFET turn—on time. When the V_{FB} is higher than 2 V and the SENSEFET turn—on time is lower than 1.2 μs , the FSGM0765R recognizes this condition as an abnormal error and shuts down PWM switching until V_{CC} reaches V_{START} again. An abnormal condition output short is shown in Figure 22.

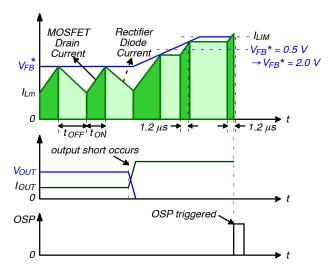


Figure 22. Output-Short Protection

Over-Voltage Protection (OVP)

If the secondary-side feedback circuit malfunctions or a solder defect causes an opening in the feedback path, the current through the opto-coupler transistor becomes almost zero. Then V_{FB} climbs up in a similar manner to the overload situation, forcing the preset maximum current to be supplied to the SMPS until the overload protection is triggered. Because more energy than required is provided to the output, the output voltage may exceed the rated voltage before the overload protection is triggered, resulting in the breakdown of the devices in the secondary side. To prevent this situation, an OVP circuit is employed. In general, the V_{CC} is proportional to the output voltage and the FSGM0765R uses V_{CC} instead of directly monitoring the output voltage. If V_{CC} exceeds 24.5 V, an OVP circuit is triggered, resulting in the termination of the switching operation. To avoid undesired activation of OVP during normal operation, V_{CC} should be designed to be below 24.5 V.

Thermal Shutdown (TSD)

The SENSEFET and the control IC on a die in one package makes it easier for the control IC to detect the over temperature of the SENSEFET. If the temperature exceeds ~140°C, the thermal shutdown is triggered and the FSGM0765R stops operation. The FSGM0765R operates in auto-restart mode until the temperature decreases to around 110°C, when normal operation resumes.

Soft Burst-Mode Operation

To minimize power dissipation in standby mode, the FSGM0765R enters burst-mode operation. As the load decreases, the feedback voltage decreases. As shown in Figure 23, the device automatically enters burst mode when the feedback voltage drops below V_{BURL} (400 mV). At this point, switching stops and the output voltages start to drop at a rate dependent on standby current load. This causes the feedback voltage to rise. Once it passes V_{BURH} (600 mV), switching resumes. At this point, the drain current peak increases gradually. This soft burst-mode can reduce audible noise during burst-mode operation. The feedback voltage then falls and the process repeats. Burst-mode operation alternately enables and disables switching of the SENSEFET, thereby reducing switching loss in standby mode.

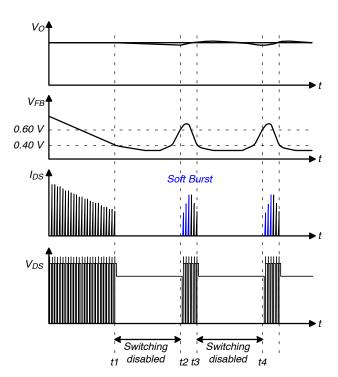


Figure 23. Burst-Mode Operation

TYPICAL APPLICATION CIRCUIT

Table 2. TYPICAL APPLICATION CIRCUIT

Application	Input Voltage	Rated Output	Rated Power
LCD TV, Monitor Power Supply	85 ~ 265 V _{AC}	5.0 V (2.6 A) 14.0 V (3.0 A)	5 W

Key Design Notes:

- 1. The delay time for overload protection is designed to be about 30 ms with C105 (27 nF). OLP time between 25 ms (22 nF) and 50 ms (43 nF) is recommended.
- 2. The SMD–type capacitor (C106) must be placed as close as possible to the V_{CC} pin to avoid malfunction by abrupt pulsating noises and to improve ESD and surge immunity. Capacitance between 100 nF and 220 nF is recommended.

Schematic

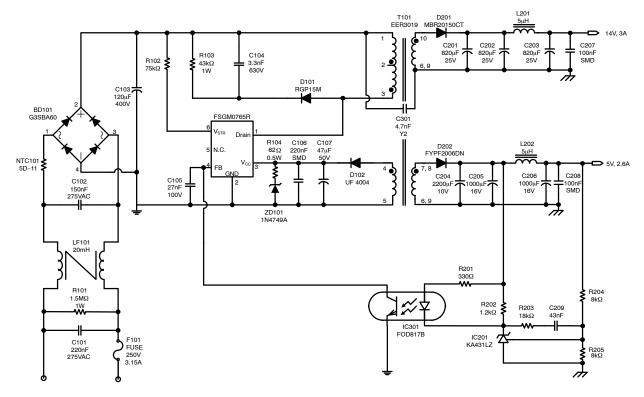


Figure 24. Schematic of Demonstration Board

Transformer

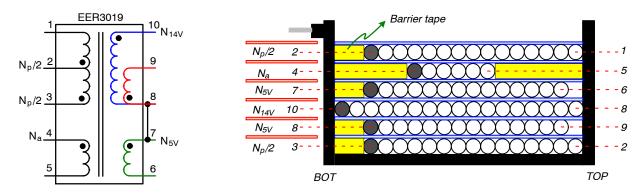


Figure 25. Schematic of Transformer

Winding Specification

Table 3. WINDING SPECIFICATION

						Barrier Tape	
	Pin (S → F)	Wire	Turns	Winding Method	TOP	вот	Ts
N _p /2	3 → 2	0.37 φ x 1	20	Solenoid Winding		2.0 mm	1
Insulation: Polyester Tape t = 0.025 mm, 2 Layers							
N _{5V}	8 → 9	0.4 φ x 3 (TIW)	3	Solenoid Winding		2.0 mm	1
Insulation: Po	Insulation: Polyester Tape t = 0.025 mm, 2 Layers				-		
N _{14V}	10 → 8	0.4 φ x 3 (TIW)	5	Solenoid Winding			
Insulation: Po	olyester Tape t =	0.025 mm, 2 Layers				•	
N _{5V}	7 → 6	0.4 φ x 3 (TIW)	3	Solenoid Winding		2.0 mm	1
Insulation: Po	olyester Tape t =	0.025 mm, 2 Layers					
Na	4 → 5	0.2 φ x 1	6	Solenoid Winding	4.0 mm	4.0 mm	1
Insulation: Polyester Tape t = 0.025 mm, 2 Layers					•		
N _p /2	2 → 1	0.37 φ x 1	20	Solenoid Winding		2.0 mm	1
Insulation: Po	olyester Tape t =	0.025 mm, 2 Layers				•	

Electrical Characteristics

Table 4. ELECTRICAL CHARACTERISTICS

	Pin	Specification	Remark
Inductance	1 – 3	670 μH ±6%	67 kHz, 1 V
Leakage	1 – 3	15 μH Maximum	Short All Other Pins

Core & Bobbin

• Core: EER3019 (Ae = 134.0 mm²) • Bobbin: EER3019

Bill of Materials

Table 5. Bill of Materials

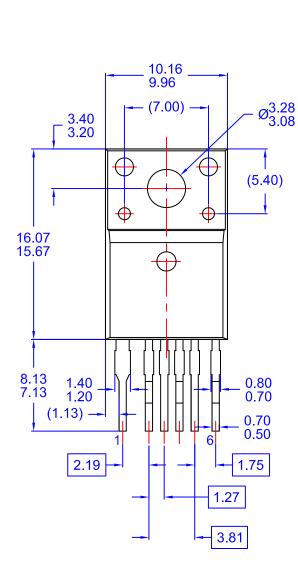
Part #	Value	Note					
	Fuse						
F101	250 V 3.15 A						
NTC							
NTC101	5D-11	DSC					
	Resistor						
R101	1.5 MΩ, J	0.5 W					
R102	75 kΩ, J	1/2 W					
R103	43 kΩ, J	1 W					
R104	62 Ω, J	1/2 W					
R201	330 Ω, J	1/4 W					
R202	1.2 kΩ, F	1/4 W, 1%					
R203	18 kΩ, F	1/4 W, 1%					
R204	8 kΩ, F	1/4 W, 1%					
R205	8 kΩ, F	1/4 W, 1%					
	IC						
FSGM0765R	FSGM0765R	ON Semiconductor					
IC201	KA431LZ	ON Semiconductor					
IC301	FOD817B	ON Semiconductor					
	Diode						
D101	RGP15M	Vishay					
D102	UF4004	Vishay					
ZD101	1N4749	Vishay					
D201	MBR20150CT	ON Semiconductor					
D202	FYPF2006DN	ON Semiconductor					
BD101	G3SBA60	Vishay					

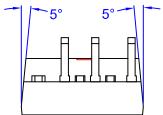
Part #	Value	Note				
	Capacitor					
C101	220 nF / 275 V	Box (Pilkor)				
C102	150 nF / 275 V	Box (Pilkor)				
C103	120 μF / 400 V	Electrolytic (SamYoung)				
C104	3.3 nF / 630 V	Film (Sehwa)				
C105	27 nF / 100 V	Film (Sehwa)				
C106	220 nF	SMD (2012)				
C107	47 μF / 50 V	Electrolytic (SamYoung				
C201	820 μF / 25 V	Electrolytic (SamYoung				
C202	820 μF / 25 V	Electrolytic (SamYoung				
C203	820 μF / 25 V	Electrolytic (SamYoung				
C204	2200 μF / 10 V	Electrolytic (SamYoung				
C205	1000 μF / 16 V	Film (Sehwa)				
C206	1000 μF / 16 V	SMD (2012)				
C207	47 nF / 100 V	SMD (2012)				
C208	100 nF	SMD (2012)				
C209	100 nF	SMD (2012)				
C301	4.7 nF / Y2	Y-cap (Samhwa)				
	Inductor					
LF101	20 mH	Line filter 0.5Ø				
L201	5 μΗ	5A Rating				
L202	5 μΗ	5A Rating				
	Jumper					
J101						
	Transformer					
T101	670 μΗ					

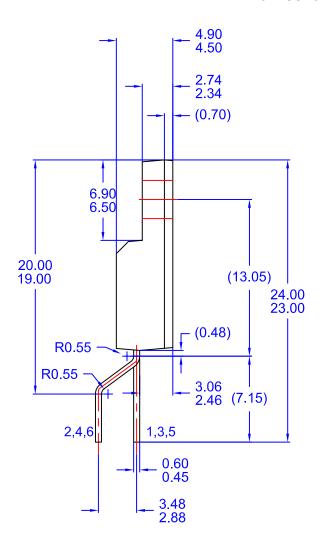
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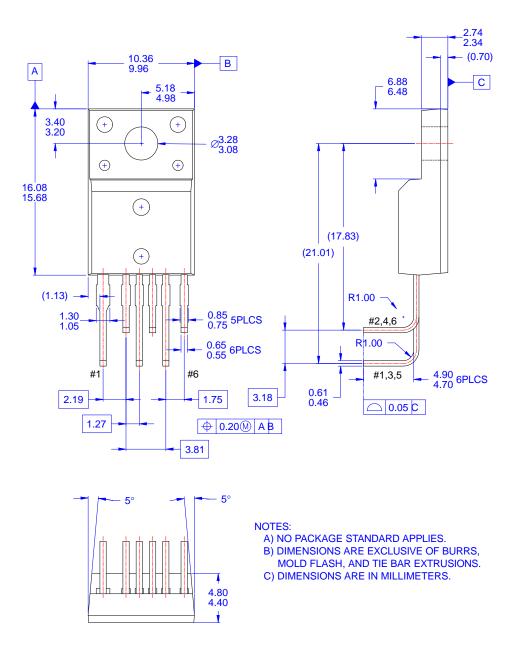
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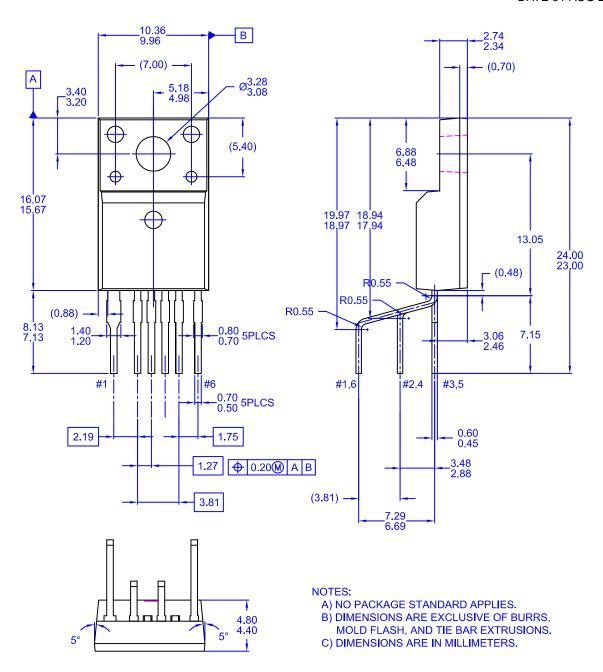
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